查询62000供应商

| **62000** GaAs LIGHT EMITTING DIODE "PILL PACK" (TYPE GS1140) | **Mii** OPTOELECTRONIC PRODUCTS DIVISION |
|---|---|

| **Features:** | **Applications** |
|---|---|
| • Hermetically sealed<br>• High output, 940nm<br>• Small package<br>• PC board mountable<br>• Spectrally matched to the 61055 series detector | • Incremental encoding<br>• Reflective sensors<br>• Position sensors<br>• Level sensors |

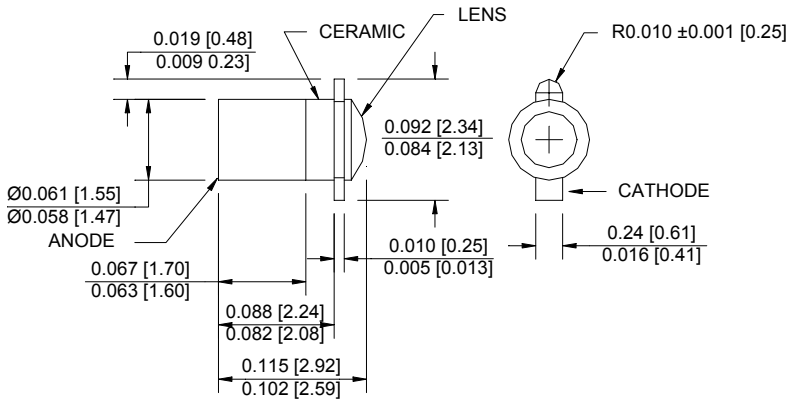
## DESCRIPTION

The ***62000*** is a P-N GaAs Infrared Light Emitting Diode in a lensed "pill" package designed to be mounted in a double-clad printed circuit board. It is spectrally and mechanically matched to companion phototransistors and photodarlingtons with it's narrow beam angle lens and small size which make it ideal for use in optical encoders, card reader arrays, etc. Available binned to customer specifications and/or screened to MIL-PRF-19500.

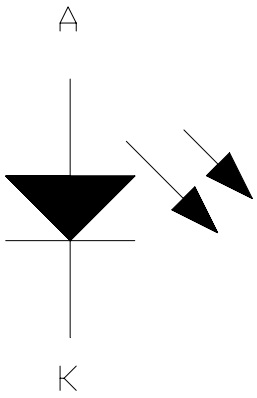
## ABSOLUTE MAXIMUM RATINGS

Storage Temperature.....-65°C to +150°C
Operating Temperature .....-65°C to +125°C
Reverse Voltage( at 25°C case temperature) ..... 2Vdc
Forward Current-Continuous ..... 100mA
Soldering Temperature (3 Minutes) ..... 240°C

**Package Dimensions** **Schematic Diagram**




ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

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## ELECTRICAL CHARACTERISTICS

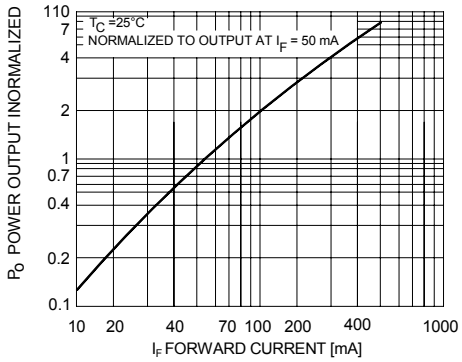
$T_A$ = 25°C unless otherwise specified.

| PARAMETER | | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS | NOTE |
|---|---|---|---|---|---|---|---|---|
| Output Power | 62000-X01 | $P_O$ | 0.25 | 0.3 | | mW | $I_F$ = 50mA | |
| | 62000-X02 | | 0.40 | 0.65 | | | | |
| | 62000-X03 | | 1.0 | 1.2 | | | | |
| | 62000-X04 | | 1.5 | 1.6 | | | | |
| Forward Voltage | 62000-XXX | $V_F$ | | | 1.6 | V | $I_F$ =50mA | |
| Reverse Breakdown Voltage | 62000-XXX | $B_{VR}$ | 2 | | | V | $I_B$ = 10μA | |
| Radiation Rise Time | 62000-XXX | $t_R$ | | 0.7 | | μs | | |
| Peak Wavelength | 62000-XXX | $\lambda_P$ | | 940 | | nm | $I_F$ =50mA | |
| Beam Angle | 62000-XXX | θ | | 20 | | degrees | | 1 |
| Forward Max Continuous Current | 62000-XXX | $I_{F(MAX)}$ | | | 100 | mA | 25°C Case | |

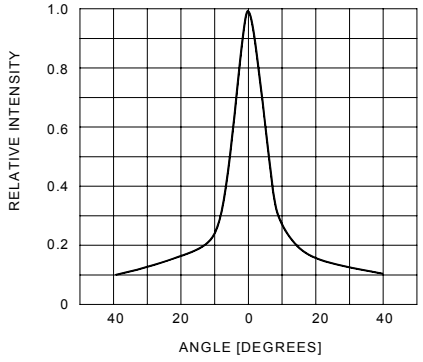
**NOTES:**

1. Low profile 40° lens also available.

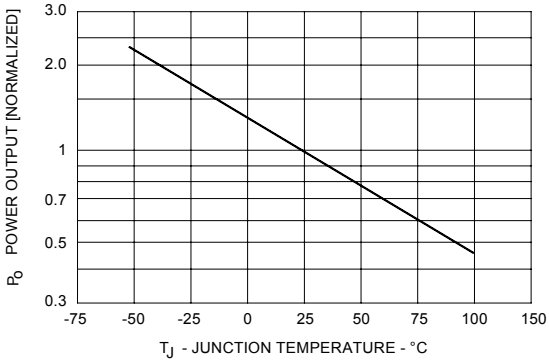
**INSTANTANEOUS POWER OUTPUT versus FORWARD CURRENT**



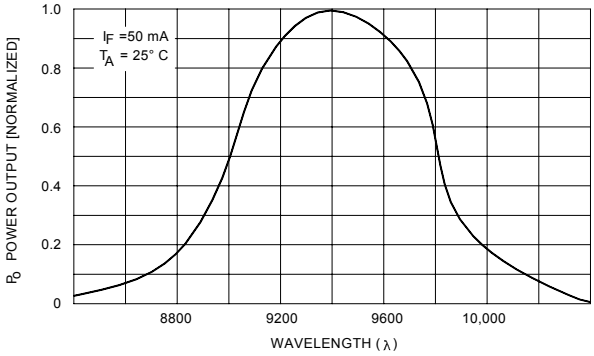

**RADIATION PATTERN**




**POWER OUTPUT versus JUNCTION TEMPERATURE**




**RELATIVE SPECTRAL OUTPUT**



## RECOMMENDED OPERATING CONDITIONS:

| PARAMETER | SYMBOL | MIN | MAX | UNITS |
|---|---|---|---|---|
| Forward Current | $I_F$ | 50 | 100 | mA |

## SELECTION GUIDE

| PART NUMBER | PART DESCRIPTION | $P_O$ Range |
|---|---|---|
| 62000-001 | GaAs LED in pill package, commercial version | +0.25 mW |
| 62000-101 | GaAsLED in pill package (-55° to +100°C) with 100% screening | +0.25 mW |
| 62000-002 | GaAs LED in pill package, commercial version | +0.4 mW |
| 62000-102 | GaAsLED in pill package (-55° to +100°C) with 100% screening | +0.4 mW |
| 62000-003 | GaAs LED in pill package, commercial version | +1 mW |
| 62000-103 | GaAsLED in pill package (-55° to +100°C) with 100% screening | +1 mW |
| 62000-004 | GaAs LED in pill package, commercial version | +1.5 mW |
| 62000-104 | GaAsLED in pill package (-55° to +100°C) with 100% screening | +1.5 mW |